



# BUK9875-100A

N-channel TrenchMOS logic level FET

19 March 2014

Product data sheet

## 1. General description

Logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

## 2. Features and benefits

- Low conduction losses due to low on-state resistance
- Q101 compliant
- Suitable for logic level gate drive sources

## 3. Applications

- 12 V, 24 V and 42 V loads
- Automotive and general purpose power switching
- Motors, lamps and solenoids

## 4. Quick reference data

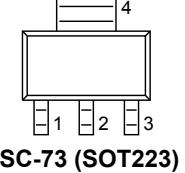
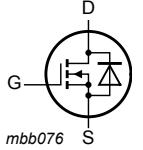
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DS}$	drain-source voltage	$T_j \geq 25^\circ\text{C}$ ; $T_j \leq 150^\circ\text{C}$	-	-	100	V
$I_D$	drain current	$V_{GS} = 5\text{ V}$ ; $T_{sp} = 25^\circ\text{C}$ ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 3</a>	-	-	7	A
$P_{tot}$	total power dissipation	$T_{sp} = 25^\circ\text{C}$ ; <a href="#">Fig. 1</a>	-	-	8	W
<b>Static characteristics</b>						
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 4.5\text{ V}$ ; $I_D = 8\text{ A}$ ; $T_j = 25^\circ\text{C}$	-	-	84	$\text{m}\Omega$
		$V_{GS} = 10\text{ V}$ ; $I_D = 8\text{ A}$ ; $T_j = 25^\circ\text{C}$	-	62	72	$\text{m}\Omega$
		$V_{GS} = 5\text{ V}$ ; $I_D = 8\text{ A}$ ; $T_j = 25^\circ\text{C}$ ; <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>	-	64	75	$\text{m}\Omega$
<b>Avalanche ruggedness</b>						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 7\text{ A}$ ; $V_{sup} \leq 100\text{ V}$ ; $R_{GS} = 50\text{ }\Omega$ ; $V_{GS} = 5\text{ V}$ ; $T_{j(init)} = 25^\circ\text{C}$ ; unclamped	-	-	49	$\text{mJ}$

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## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain		
3	S	source		
4	D	drain		

## 6. Ordering information

Table 3. Ordering information

Type number	Package			Version
	Name	Description	Version	
BUK9875-100A	SC-73	plastic surface-mounted package with increased heatsink; 4 leads		SOT223
BUK9875-100A/CU	SC-73	plastic surface-mounted package with increased heatsink; 4 leads		SOT223

## 7. Marking

Table 4. Marking codes

Type number	Marking code
BUK9875-100A	987510A
BUK9875-100A/CU	987510

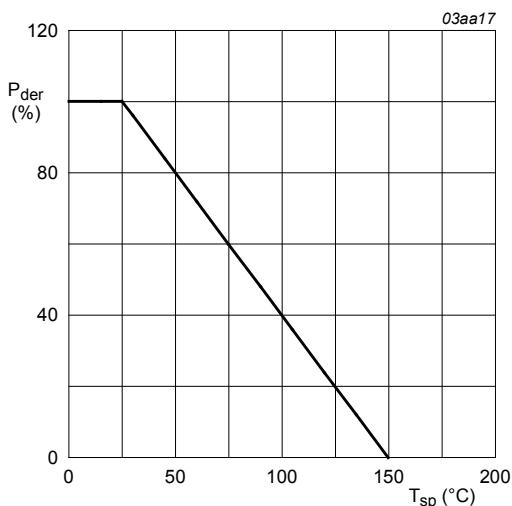
## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

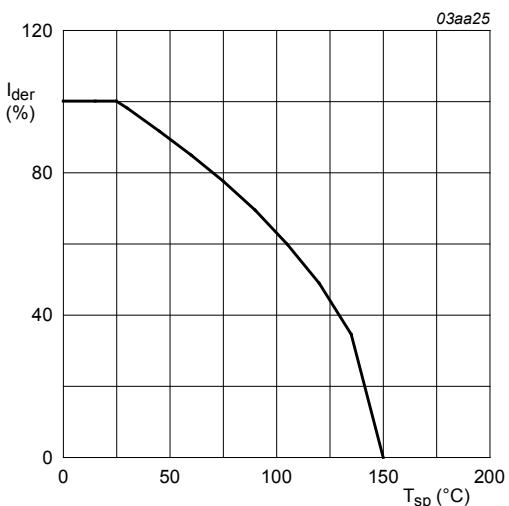
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	$T_j \geq 25^\circ\text{C}$ ; $T_j \leq 150^\circ\text{C}$	-	100	V
$V_{DGR}$	drain-gate voltage	$R_{GS} = 20\text{ k}\Omega$	-	100	V
$V_{GS}$	gate-source voltage		-10	10	V
$P_{tot}$	total power dissipation	$T_{sp} = 25^\circ\text{C}$ ; <a href="#">Fig. 1</a>	-	8	W
$I_D$	drain current	$T_{sp} = 25^\circ\text{C}$ ; $V_{GS} = 5\text{ V}$ ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 3</a>	-	7	A
		$T_{sp} = 100^\circ\text{C}$ ; $V_{GS} = 5\text{ V}$ ; <a href="#">Fig. 2</a>	-	4	A
$I_{DM}$	peak drain current	$T_{sp} = 25^\circ\text{C}$ ; pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; <a href="#">Fig. 3</a>	-	28	A

Symbol	Parameter	Conditions	Min	Max	Unit
$T_{stg}$	storage temperature		-55	150	°C
$T_j$	junction temperature		-55	150	°C
$V_{GSM}$	peak gate-source voltage	pulsed; $t_p \leq 50 \mu s$	-15	15	V
<b>Source-drain diode</b>					
$I_S$	source current	$T_{sp} = 25 \text{ }^{\circ}\text{C}$	-	7	A
$I_{SM}$	peak source current	pulsed; $t_p \leq 10 \mu s$ ; $T_{sp} = 25 \text{ }^{\circ}\text{C}$	-	28	A
<b>Avalanche ruggedness</b>					
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 7 \text{ A}$ ; $V_{sup} \leq 100 \text{ V}$ ; $R_{GS} = 50 \Omega$ ; $V_{GS} = 5 \text{ V}$ ; $T_{j(init)} = 25 \text{ }^{\circ}\text{C}$ ; unclamped	-	49	mJ



**Fig. 1. Normalized total power dissipation as a function of solder point temperature**

$$P_{der} = \frac{P_{tot}}{P_{tot}(25^{\circ}\text{C})} \times 100 \%$$



**Fig. 2. Normalized continuous drain current as a function of solder point temperature**

$$I_{der} = \frac{I_D}{I_D(25^{\circ}\text{C})} \times 100 \%$$

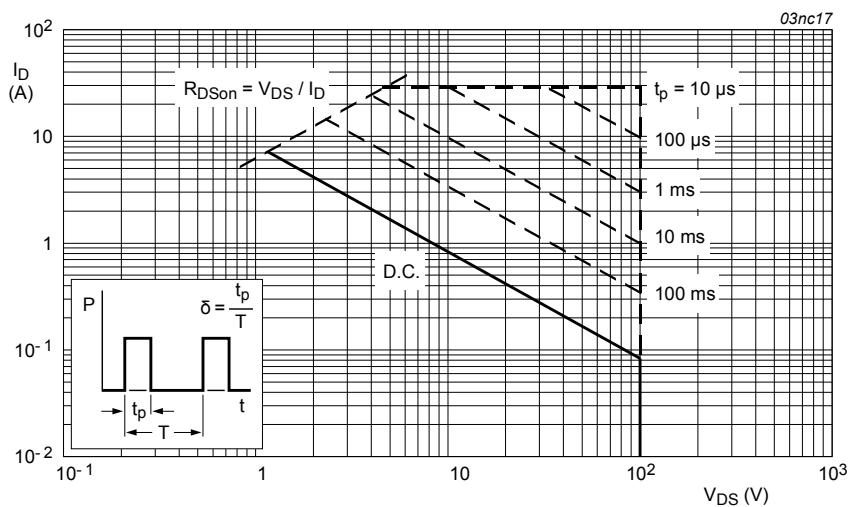


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{amb} = 25^\circ C$ ;  $I_{DM}$  is single pulse

## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	15	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	<a href="#">Fig. 4</a>	-	120	-	K/W

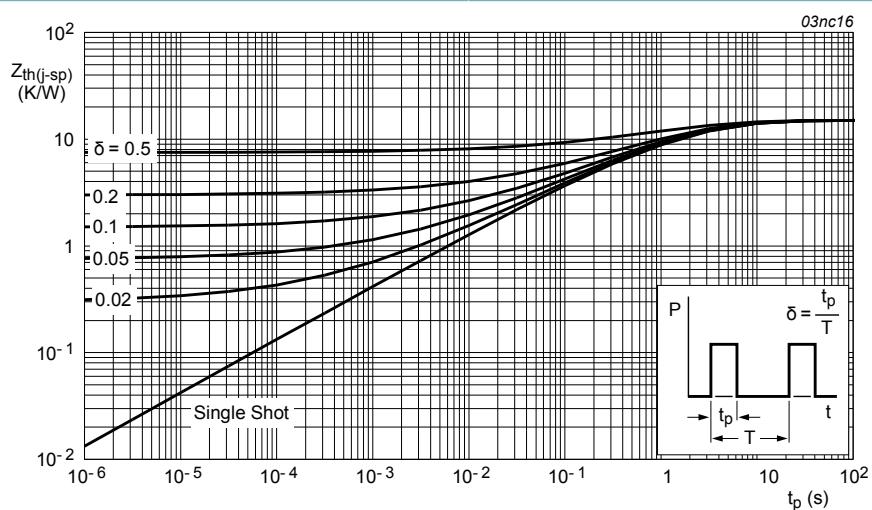
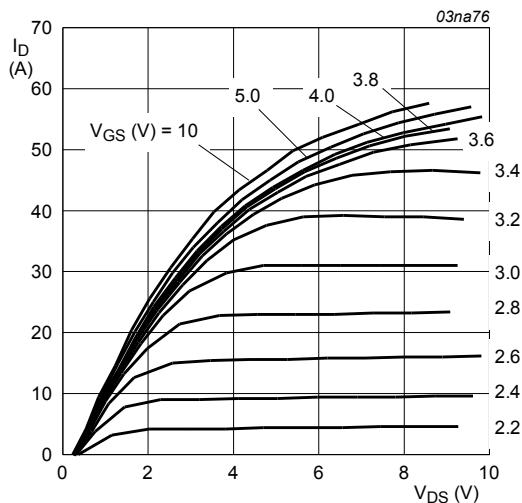


Fig. 4. Transient thermal impedance from junction to solder point as a function of pulse duration

## 10. Characteristics

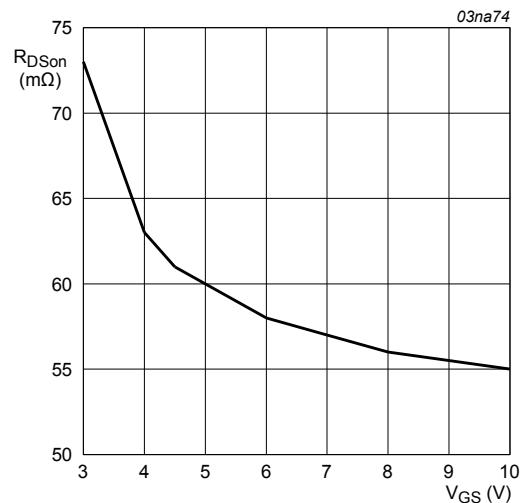
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Static characteristics</b>							
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = 0.25 mA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C		100	-	-	V
		I <sub>D</sub> = 0.25 mA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C		89	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	I <sub>D</sub> = 1 mA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C; <a href="#">Fig. 11</a>		1	1.5	2	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = -55 °C; <a href="#">Fig. 11</a>		-	-	2.3	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 150 °C; <a href="#">Fig. 11</a>		0.6	-	-	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C		-	0.05	10	µA
		V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 150 °C		-	-	500	µA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C		-	2	100	nA
		V <sub>GS</sub> = -10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C		-	2	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 5 V; I <sub>D</sub> = 8 A; T <sub>j</sub> = 150 °C; <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>		-	-	162	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 8 A; T <sub>j</sub> = 25 °C		-	-	84	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 8 A; T <sub>j</sub> = 25 °C		-	62	72	mΩ
		V <sub>GS</sub> = 5 V; I <sub>D</sub> = 8 A; T <sub>j</sub> = 25 °C; <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>		-	64	75	mΩ
<b>Dynamic characteristics</b>							
C <sub>iss</sub>	input capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 25 V; f = 1 MHz; T <sub>j</sub> = 25 °C; <a href="#">Fig. 14</a>		-	1270	1690	pF
C <sub>oss</sub>	output capacitance			-	140	167	pF
C <sub>rss</sub>	reverse transfer capacitance			-	90	124	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 30 V; R <sub>L</sub> = 1.2 Ω; V <sub>GS</sub> = 5 V; R <sub>G(ext)</sub> = 10 Ω; T <sub>j</sub> = 25 °C		-	13	-	ns
t <sub>r</sub>	rise time			-	120	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	58	-	ns
t <sub>f</sub>	fall time			-	57	-	ns
<b>Source-drain diode</b>							
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 5 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C; <a href="#">Fig. 15</a>		-	0.85	1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 20 A; dI <sub>S</sub> /dt = -100 A/µs; V <sub>GS</sub> = -10 V; V <sub>DS</sub> = 30 V; T <sub>j</sub> = 25 °C		-	63	-	ns
Q <sub>r</sub>	recovered charge			-	220	-	nC



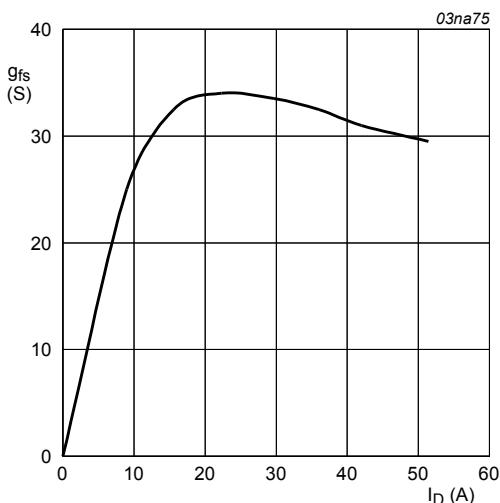
**Fig. 5. Output characteristics: drain current as a function of drain-source voltage; typical values**

$T_j = 25^\circ C$



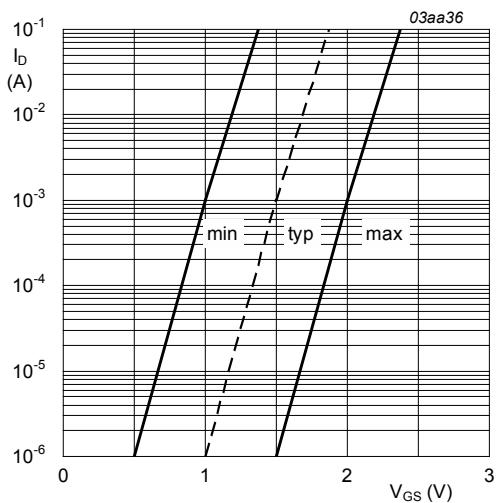
**Fig. 6. Drain-source on-state resistance as a function of gate-source; typical values**

$T_j = 25^\circ C; I_D = 8A$



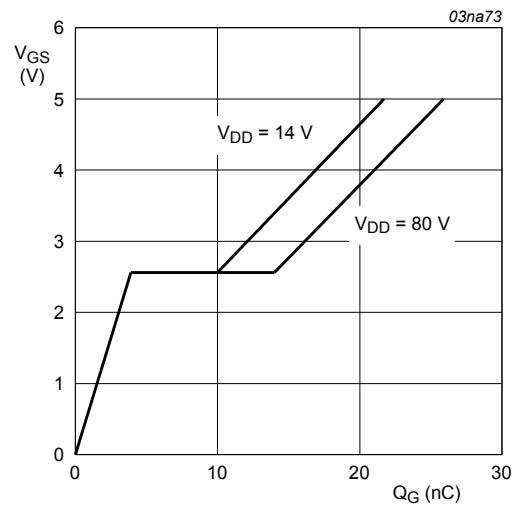
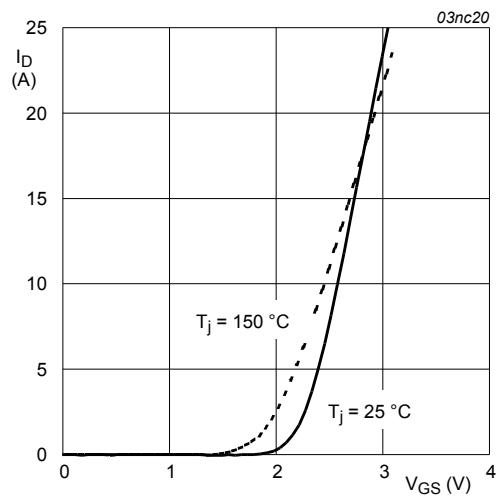
**Fig. 7. Forward transconductance as a function of drain current; typical values**

$T_j = 25^\circ C; V_{DS} = 25V$



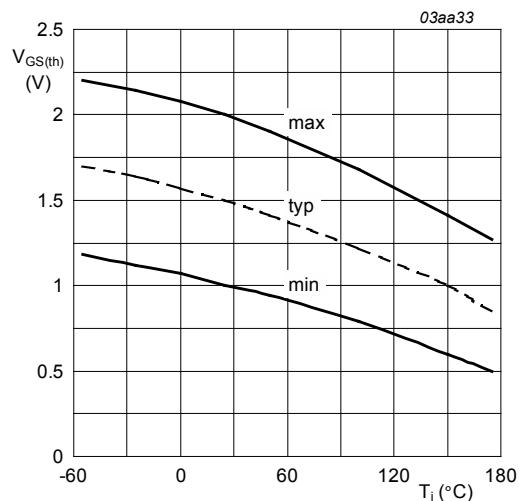
**Fig. 8. Sub-threshold drain current as a function of gate-source voltage**

$T_j = 25^\circ C; V_{DS} = 5 V$

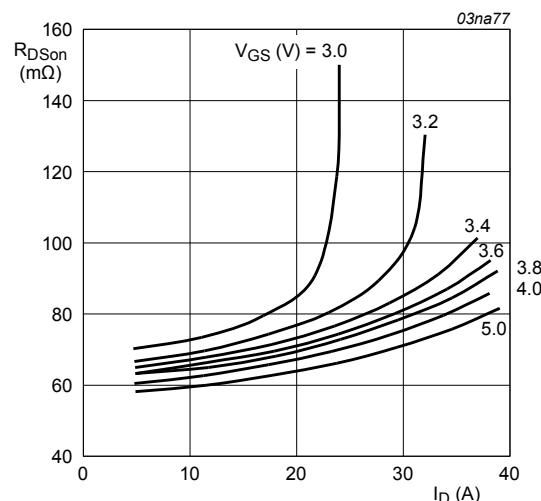


$V_{DS} = 25V$

$T_j = 25^\circ C; I_D = 20A$



$I_D = 1mA; V_{DS} = V_{GS}$



$T_j = 25^\circ C$

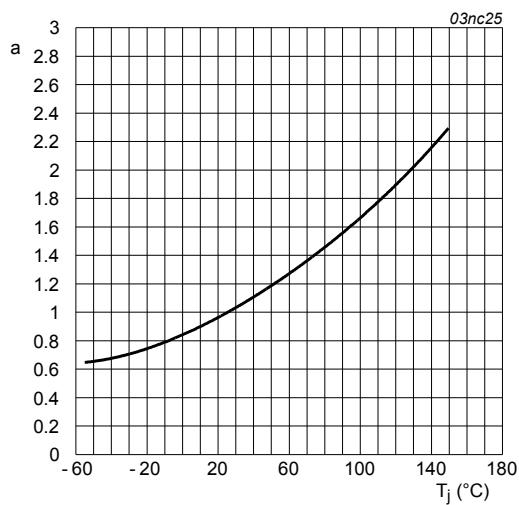


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

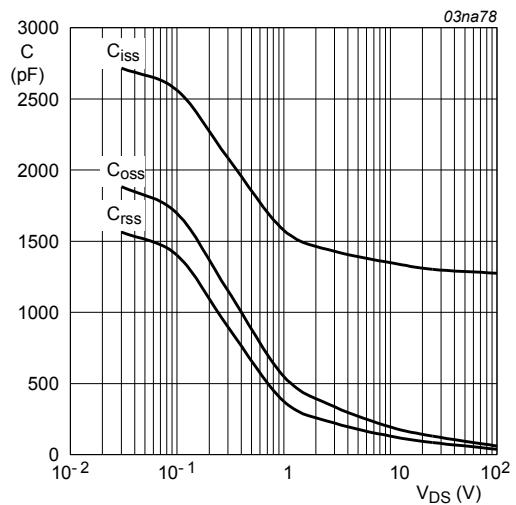


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$V_{GS} = 0V; f = 1MHz$

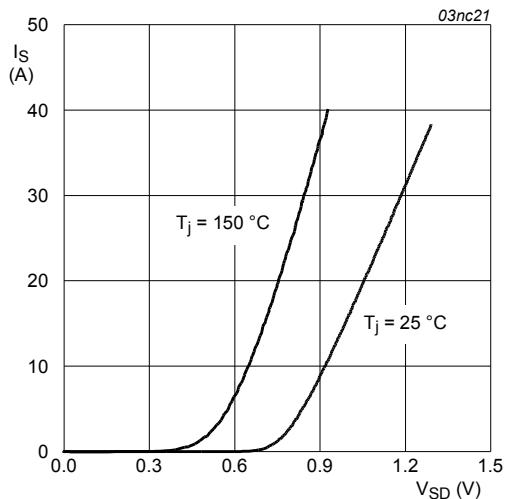


Fig. 15. Reverse diode current as a function of reverse diode voltage; typical value

$V_{GS} = 0V$

## 11. Package outline

Plastic surface-mounted package with increased heatsink; 4 leads

SOT223

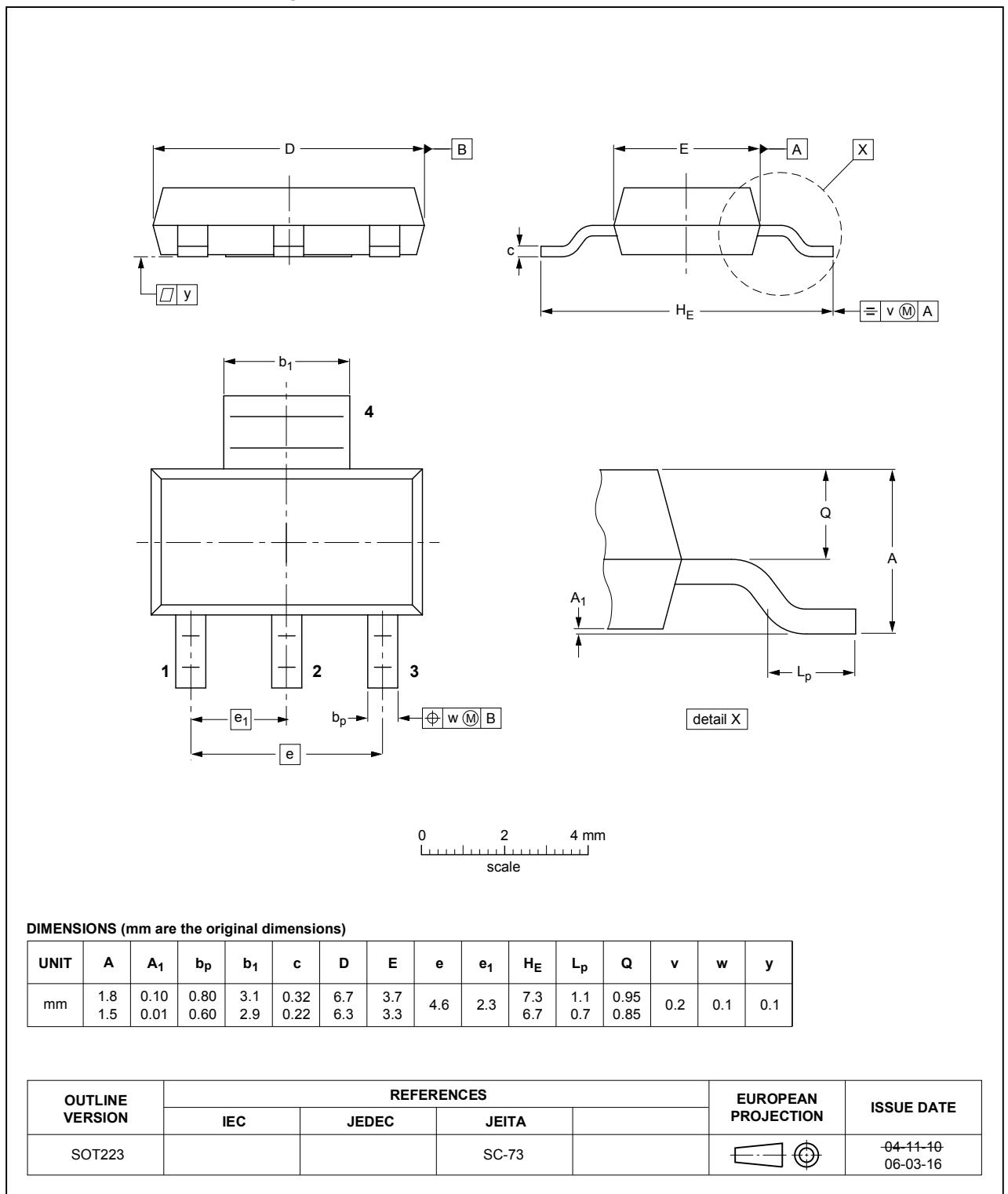


Fig. 16. Package outline SC-73 (SOT223)

## 12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 19 March 2014

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# OCEAN CHIPS

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(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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